NSN 5961-00-614-1417

Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Metal
Overall Length:
Between 0.350 inches and 0.370 inches
Геrminal Length:
1.125 inches
Overall Diameter:
Between 0.210 inches and 0.230 inches
Mounting Method:
Геrminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
10.0 reverse voltage, peak
Current Rating Per Characteristic:
0.50 microamperes source cutoff current preset
Power Rating Per Characteristic:
150.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Ferminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
30131-release1348 professional/industrial association specification
Shelf Life:
N/a
Jnit Of Measure:
-
Demilitarization:
No
Filg:
A110a0